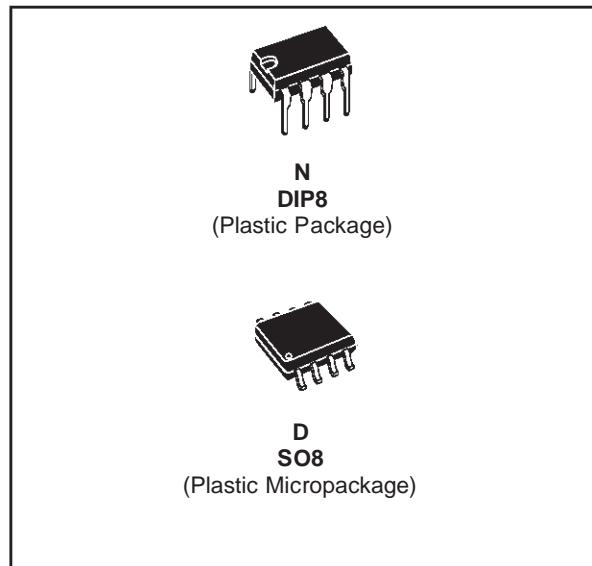




LF153  
LF253 - LF353

## WIDE BANDWIDTH DUAL J-FET OPERATIONAL AMPLIFIERS

- LOW POWER CONSUMPTION
- WIDE COMMON-MODE (UP TO  $V_{CC}^+$ ) AND DIFFERENTIAL VOLTAGE RANGE
- LOW INPUT BIAS AND OFFSET CURRENT
- OUTPUT SHORT-CIRCUIT PROTECTION
- HIGH INPUT IMPEDANCE J-FET INPUT STAGE
- INTERNAL FREQUENCY COMPENSATION
- LATCH UP FREE OPERATION
- HIGH SLEW RATE : 16V/ $\mu$ s (typ)

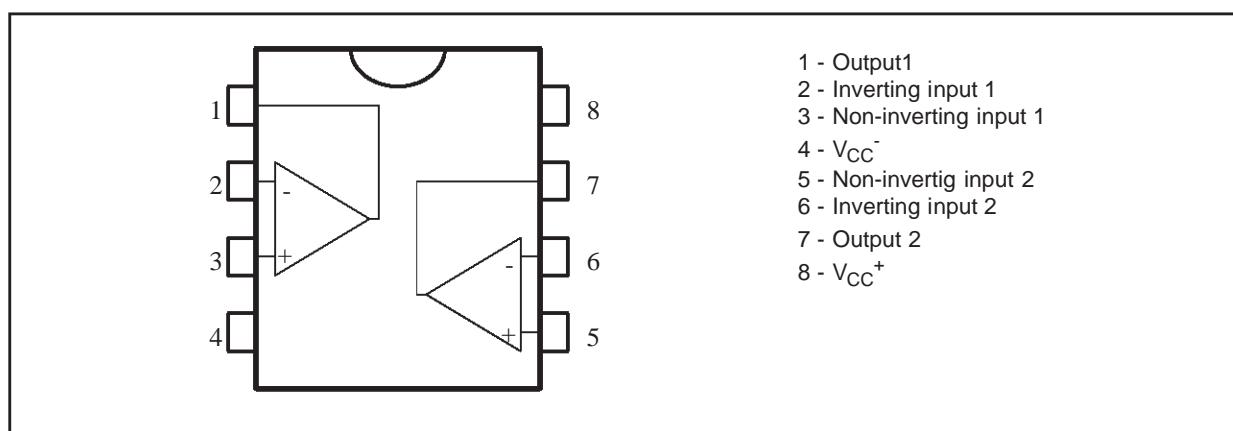


### DESCRIPTION

The LF353 are high speed J-FET input dual operational amplifiers incorporating well matched, high voltage J-FET and bipolar transistors in a monolithic integrated circuit.

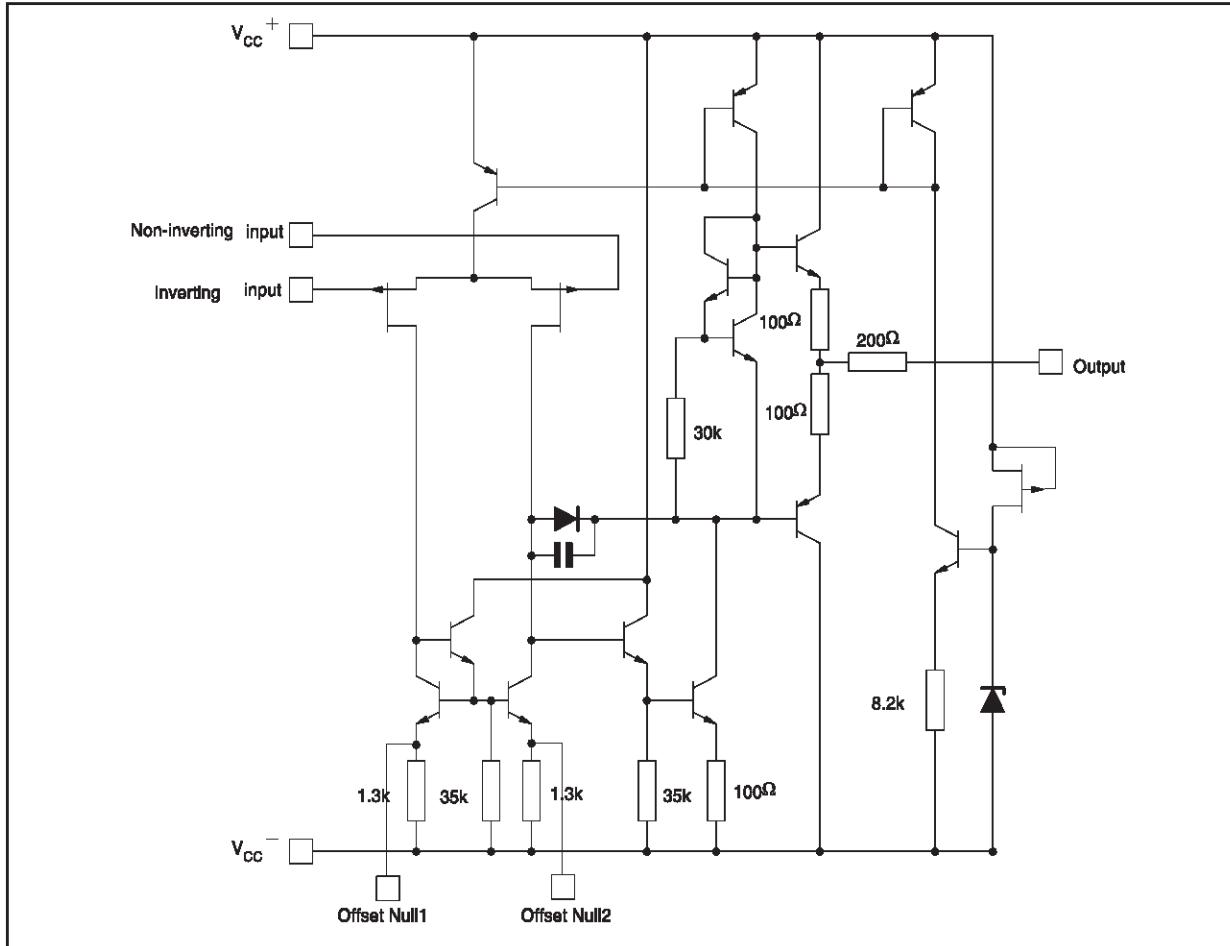
The devices feature high slew rates, low input bias and offset currents, and low offset voltage temperature coefficient.

### PIN CONNECTIONS (top view)



## LF153 - LF253 - LF353

### SCHEMATIC DIAGRAM (each amplifier)



### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	LF153	LF253	LF353	Unit
V <sub>CC</sub>	Supply voltage - note 1)		±18		V
V <sub>i</sub>	Input Voltage - note 2)		±15		V
V <sub>id</sub>	Differential Input Voltage - note 3)		±30		V
P <sub>tot</sub>	Power Dissipation		680		mW
	Output Short-circuit Duration - note 4)		Infinite		
T <sub>oper</sub>	Operating Free-air Temperature Range	-55 to +125	-40 to +105	0 to +70	°C
T <sub>stg</sub>	Storage Temperature Range		-65 to +150		°C

1. All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between V<sub>CC</sub><sup>+</sup> and V<sub>CC</sub><sup>-</sup>.

2. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.

3. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.

4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded

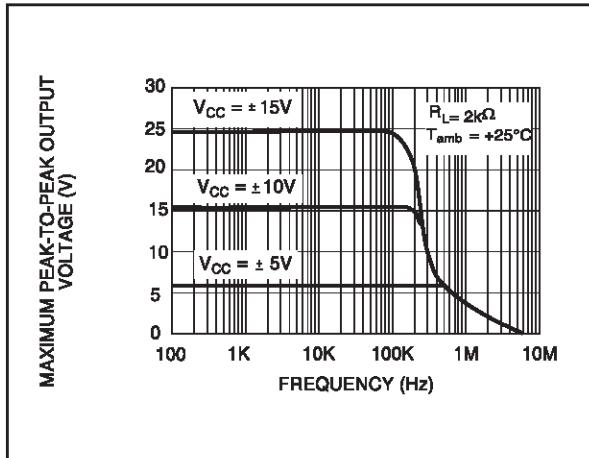
**ELECTRICAL CHARACTERISTICS** $V_{CC} = \pm 15V, T_{amb} = +25^\circ C$  (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
$V_{io}$	Input Offset Voltage ( $R_S = 10k\Omega$ ) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		3	10 13	mV
$DV_{io}$	Input Offset Voltage Drift		10		$\mu V/^\circ C$
$I_{io}$	Input Offset Current- note 1) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		5	100 4	pA nA
$I_{ib}$	Input Bias Current -note 1 $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		20	200 20	nA
$A_{vd}$	Large Signal Voltage Gain ( $R_L = 2k\Omega, V_o = \pm 10V$ ) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	50 25	200		V/mV
SVR	Supply Voltage Rejection Ratio ( $R_S = 10k\Omega$ ) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	80 80	86		dB
$I_{cc}$	Supply Current, no load $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		1.4	3.2 3.2	mA
$V_{icm}$	Input Common Mode Voltage Range	$\pm 11$	+15 -12		V
CMR	Common Mode Rejection Ratio ( $R_S = 10k\Omega$ ) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	70 70	86		dB
$I_{os}$	Output Short-circuit Current $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	10 10	40	60 60	mA
$\pm V_{opp}$	Output Voltage Swing $T_{amb} = +25^\circ C$ $R_L = 2k\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$	10 12 10 12	12 13.5		V
SR	Slew Rate $V_i = 10V, R_L = 2k\Omega, C_L = 100pF, T_{amb} = +25^\circ C$ , unity gain	12	16		V/ $\mu s$
$t_r$	Rise Time $V_i = 20mV, R_L = 2k\Omega, C_L = 100pF, T_{amb} = +25^\circ C$ , unity gain		0.1		$\mu s$
$K_{ov}$	Overshoot $V_i = 20mV, R_L = 2k\Omega, C_L = 100pF, T_{amb} = +25^\circ C$ , unity gain		10		%
GBP	Gain Bandwidth Product $f = 100kHz, T_{amb} = +25^\circ C, V_{in} = 10mV, R_L = 2k\Omega, C_L = 100pF$	2.5	4		MHz
$R_i$	Input Resistance		$10^{12}$		$\Omega$
THD	Total Harmonic Distortion ( $f = 1kHz, A_v = 20dB$ $R_L = 2k\Omega, C_L = 100pF, T_{amb} = +25^\circ C, V_o = 2V_{pp}$ )		0.01		
$e_n$	Equivalent Input Noise Voltage $R_S = 100\Omega, f = 1KHz$		15		$\frac{nV}{\sqrt{Hz}}$
$\emptyset m$	Phase Margin		45		Degrees
$V_{o1}/V_{o2}$	Channel Separation ( $A_v = 100, T_{amb} = +25^\circ C$ )		120		dB

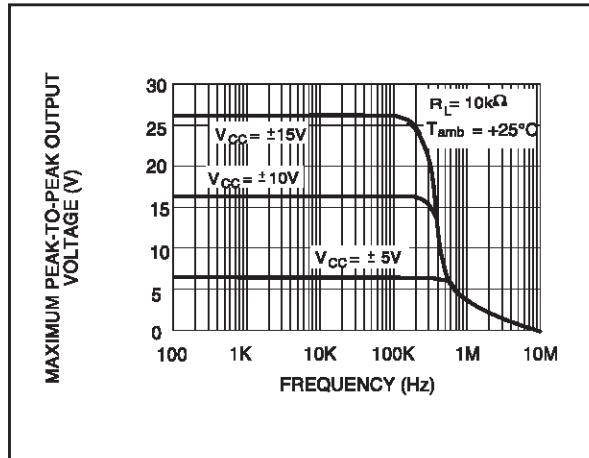
1. The input bias currents are junction leakage currents which approximately double for every  $10^\circ C$  increase in the junction temperature.

## LF153 - LF253 - LF353

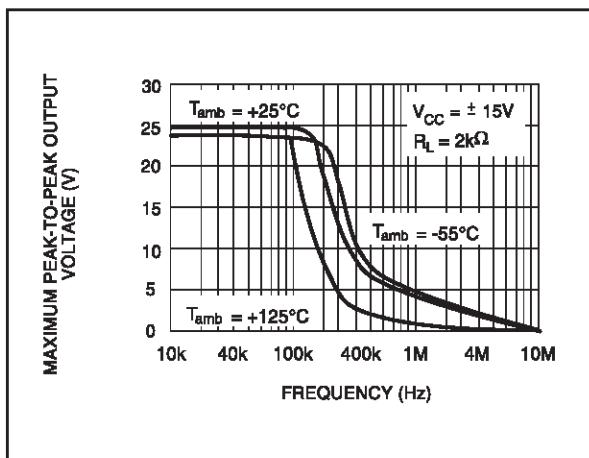
**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY**



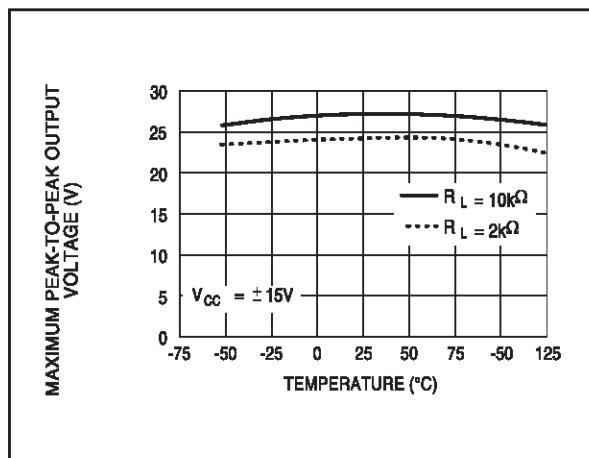
**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY**



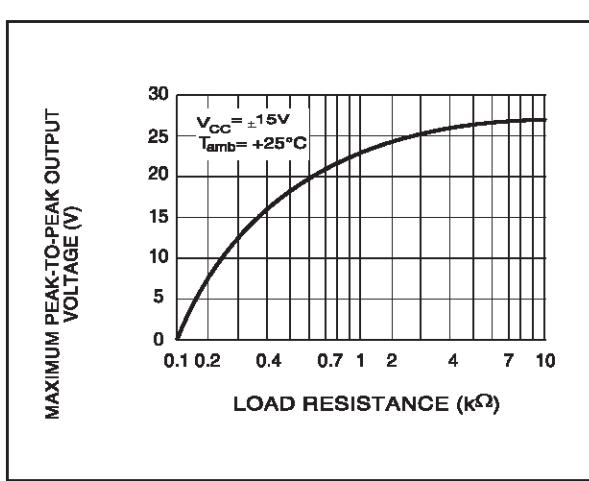
**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY**



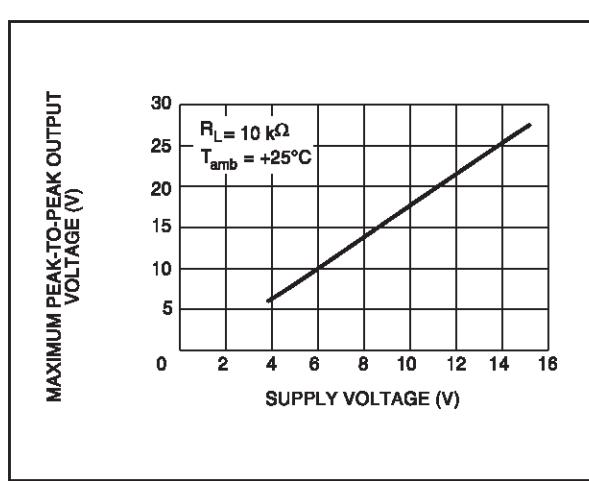
**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREE AIR TEMP.**



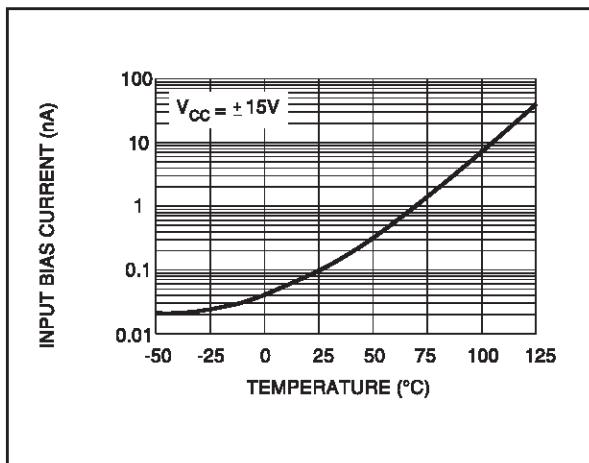
**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus LOAD RESISTANCE**



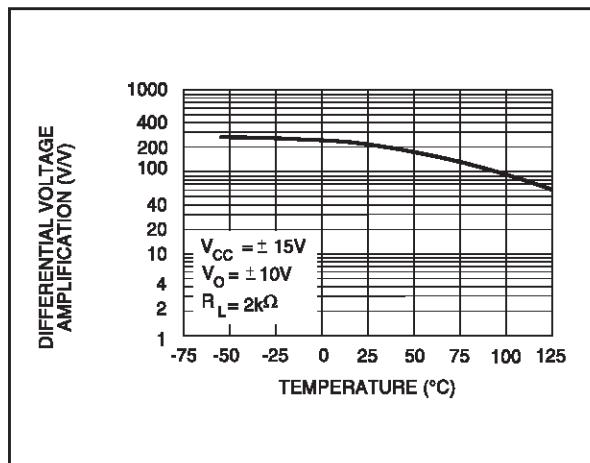
**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus SUPPLY VOLTAGE**



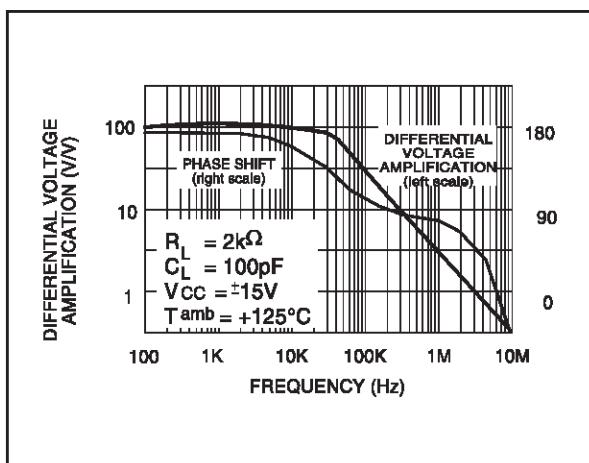
**INPUT BIAS CURRENT versus FREE AIR TEMPERATURE**



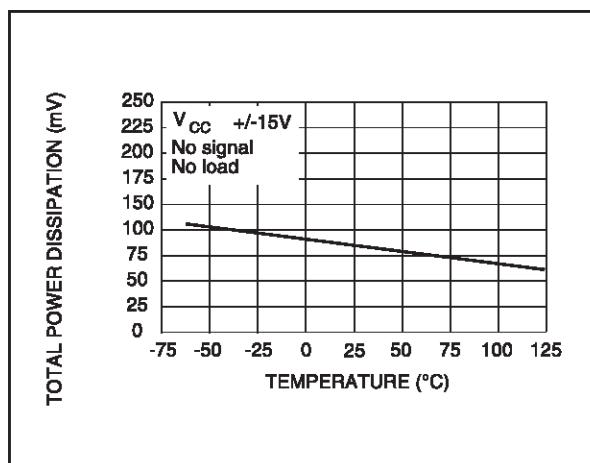
**LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION versus FREE AIR TEMP.**



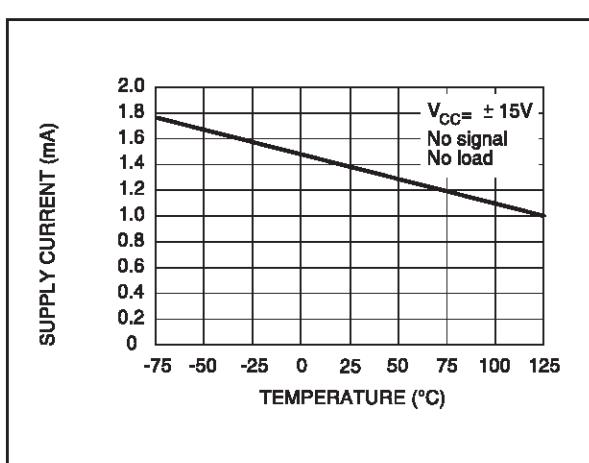
**LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT versus FREQUENCY**



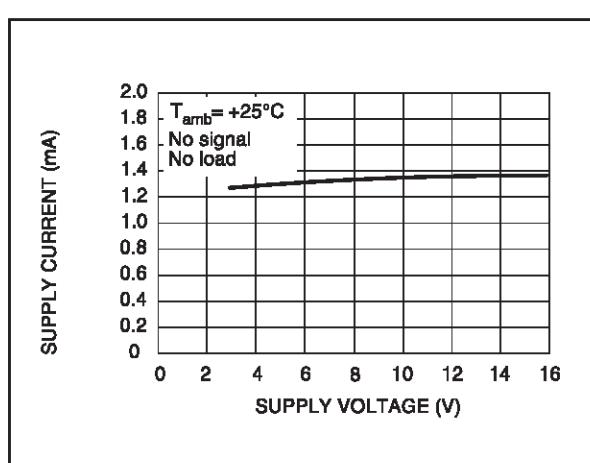
**TOTAL POWER DISSIPATION versus FREE AIR TEMPERATURE**



**SUPPLY CURRENT PER AMPLIFIER versus FREE AIR TEMPERATURE**

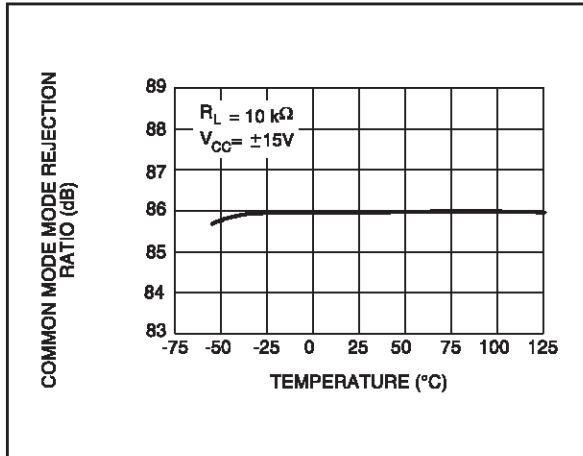


**SUPPLY CURRENT PER AMPLIFIER versus SUPPLY VOLTAGE**

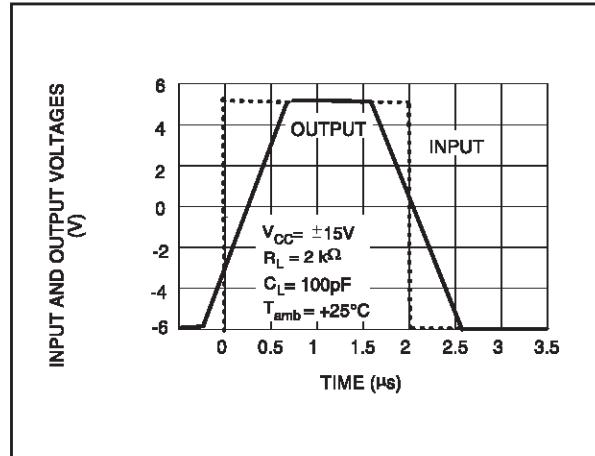


## LF153 - LF253 - LF353

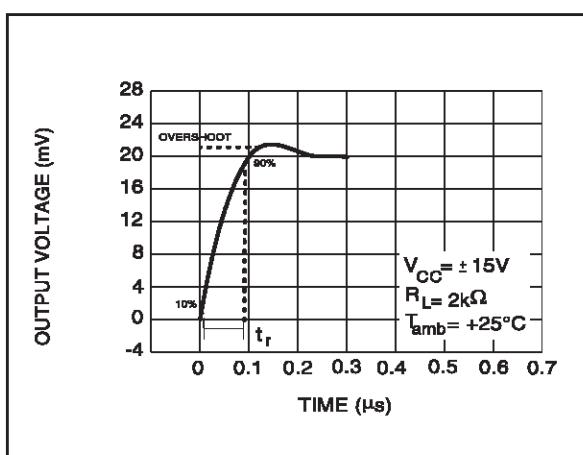
**COMMON MODE REJECTION RATIO versus  
FREE AIR TEMPERATURE**



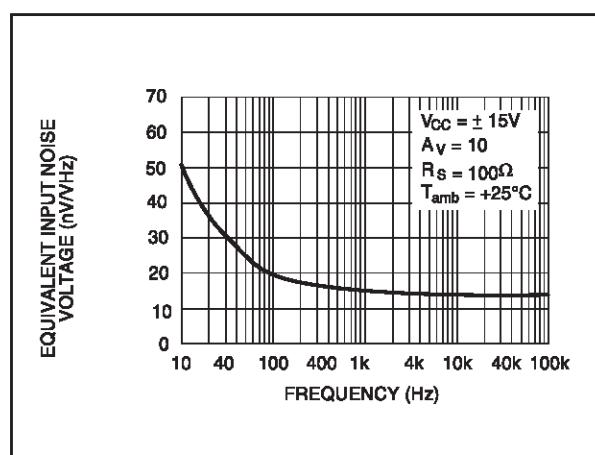
**VOLTAGE FOLLOWER LARGE SIGNAL PULSE  
RESPONSE**



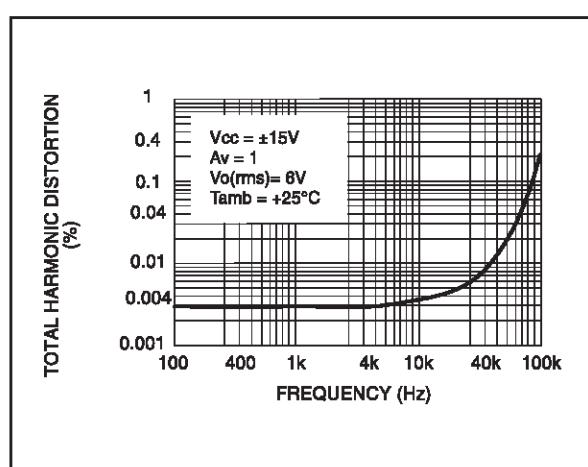
**OUTPUT VOLTAGE versus ELAPSED TIME**



**EQUIVALENT INPUT NOISE VOLTAGE versus  
FREQUENCY**



**TOTAL HARMONIC DISTORTION versus FREQUENCY**



**PARAMETER MEASUREMENT INFORMATION**

Figure 1 : Voltage Follower

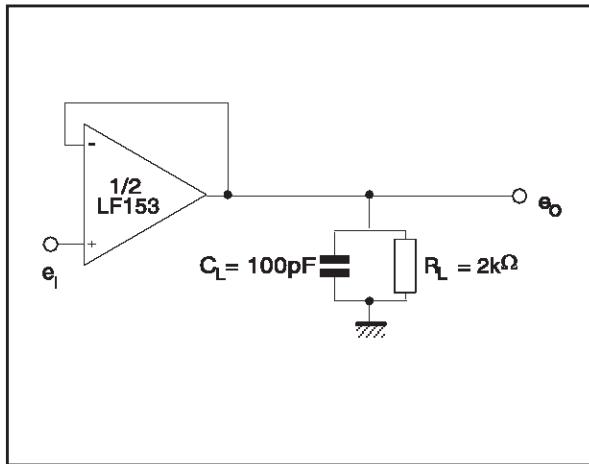
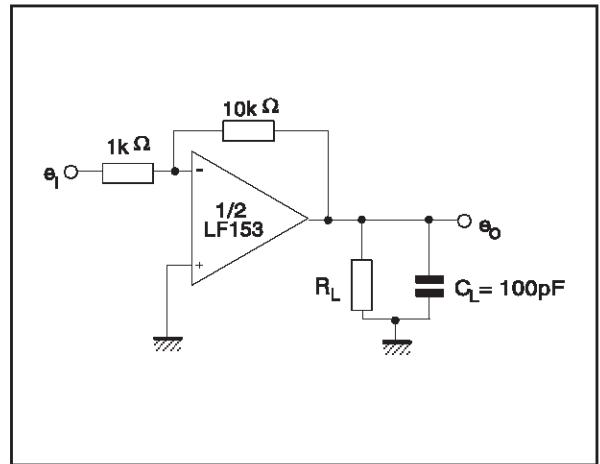
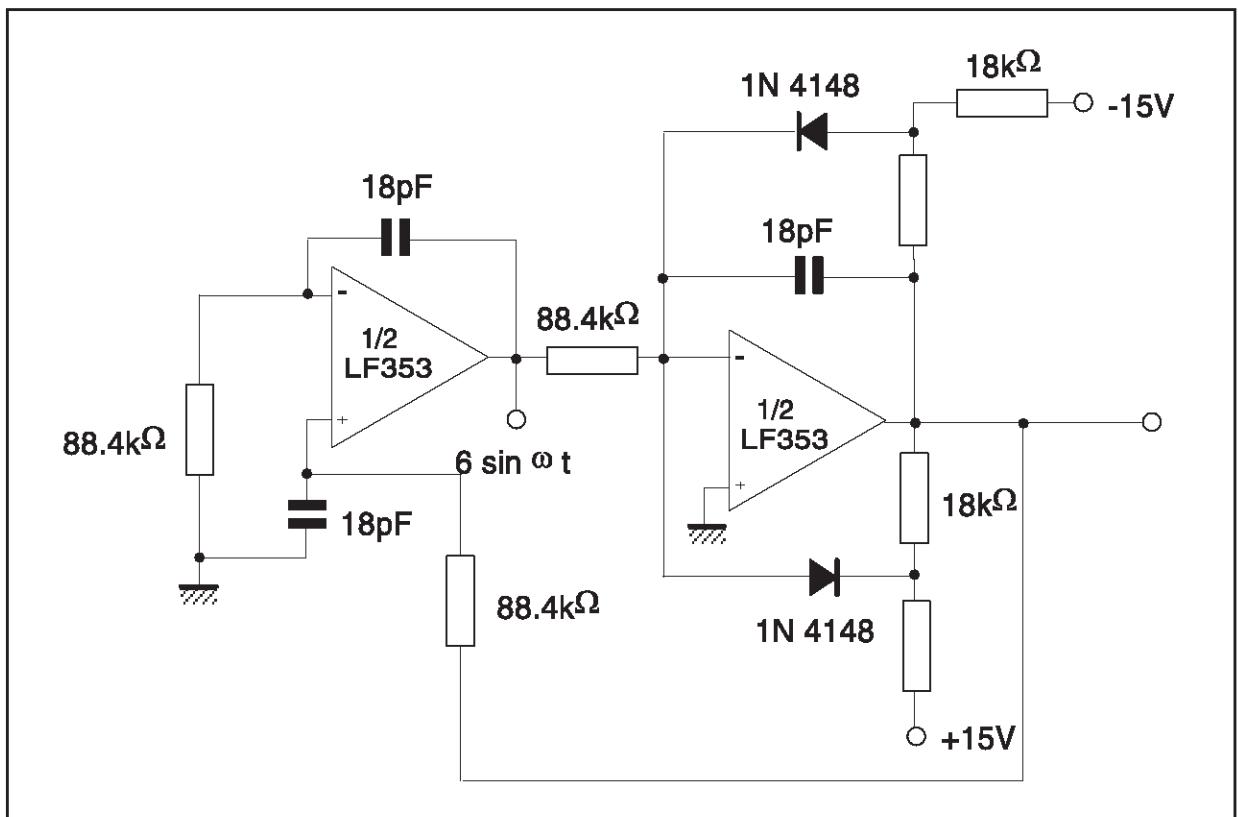


Figure 2 : Gain-of-10 inverting amplifier



**TYPICAL APPLICATION**

QUADRUPLE OSCILLATOR

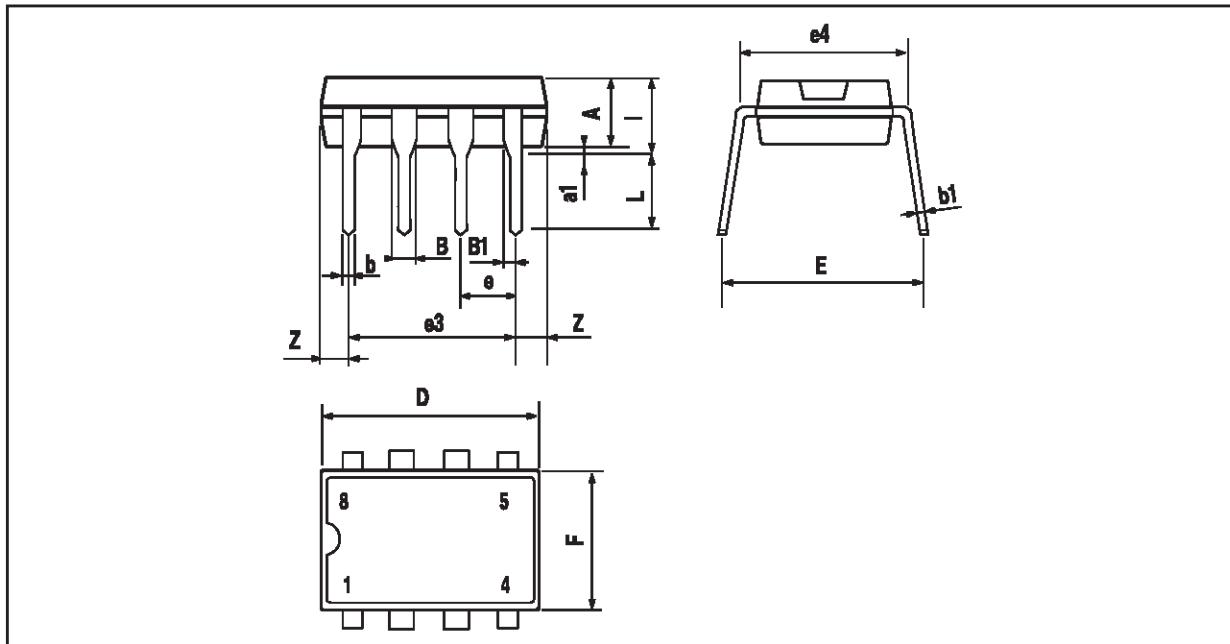


## LF153 - LF253 - LF353

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### PACKAGE MECHANICAL DATA

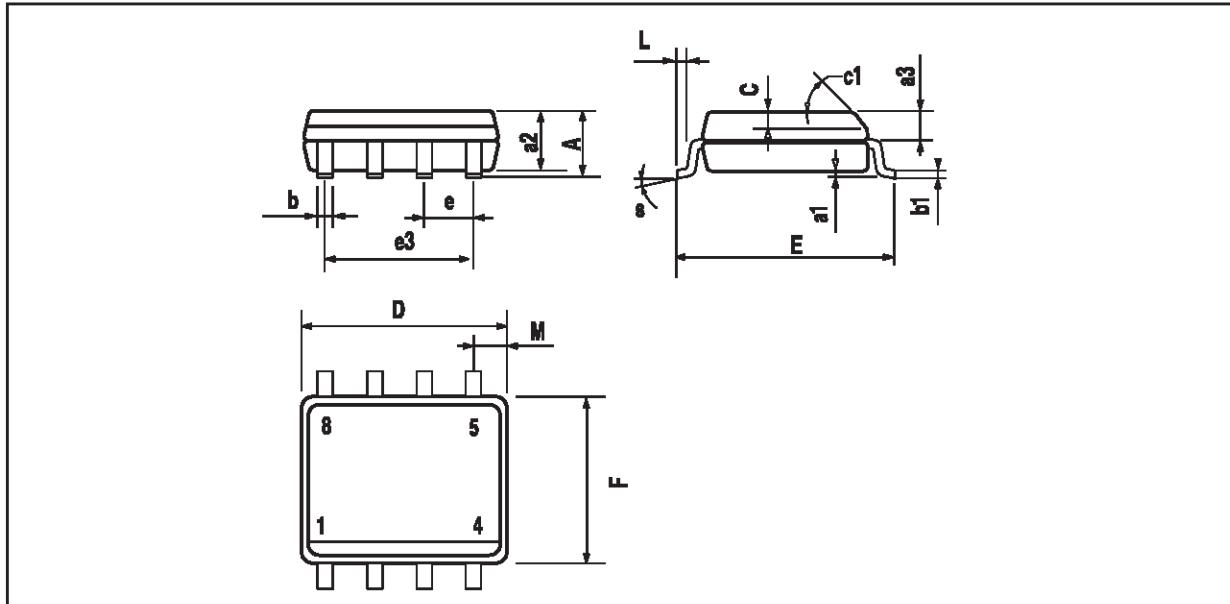
8 PINS - PLASTIC DIP



Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A		3.32			0.131	
a1	0.51			0.020		
B	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D		10.92			0.430	
E	7.95		9.75	0.313		0.384
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F		6.6			0.260	
i		5.08			0.200	
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

## PACKAGE MECHANICAL DATA

8 PINS - PLASTIC MICROPACKAGE (SO)



Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.25	0.004		0.010
a2			1.65			0.065
a3	0.65		0.85	0.026		0.033
b	0.35		0.48	0.014		0.019
b1	0.19		0.25	0.007		0.010
C	0.25		0.5	0.010		0.020
c1	45° (typ.)					
D	4.8		5.0	0.189		0.197
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		3.81			0.150	
F	3.8		4.0	0.150		0.157
L	0.4		1.27	0.016		0.050
M			0.6			0.024
S	8° (max.)					

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